

Features

 $BV_{CEO} > 25V$

BV_{CBO} > 35V forward blocking voltage

Complementary PNP Type: ZXTP749F

725mW Power dissipation

I_C = 3A high Continuous Collector Current

Low saturation voltage, V_{CE(SAT)} < 120mV @1A

 $R_{CE(SAT)}$ = 77m Ω for a low equivalent On-Resistance

hFE specified up to 6A for high current gain hold up

Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)

Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability



A Product Line of Diodes Incorporated

ZXTN649F

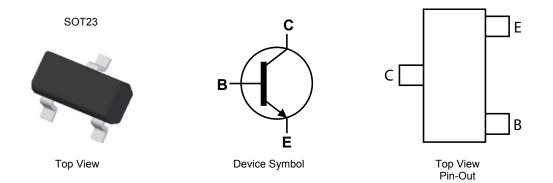
25V NPN LOW SATURATION TRANSISTOR IN SOT23

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight 0.008 grams (approximate)

Applications

- MOSFET gate drivers
- Power switching in automotive and industrial applications
- Motor drive and control



Ordering Information (Note 4)

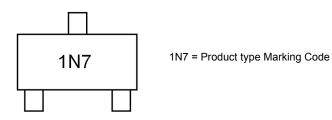
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN649FTA	1N7	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information







ZXTN649F

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	35	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ι _C	3	А
Peak Pulse Current	I _{CM}	6	А
Base Current	IB	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	725	mW
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	172	°C/W
Thermal Resistance, Junction to Leads	(Note 6)	R _{θJL}	79	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

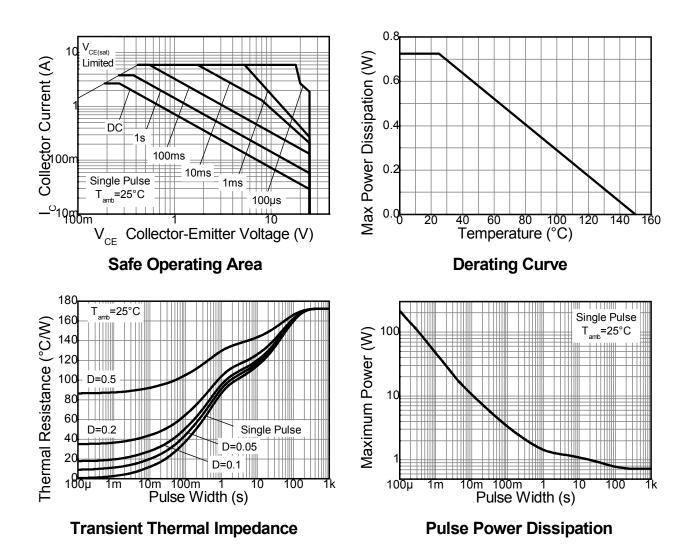
 For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
Thermal resistance from junction to solder-point (at the end of collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:







Thermal Characteristics and Derating information







ZXTN649F

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

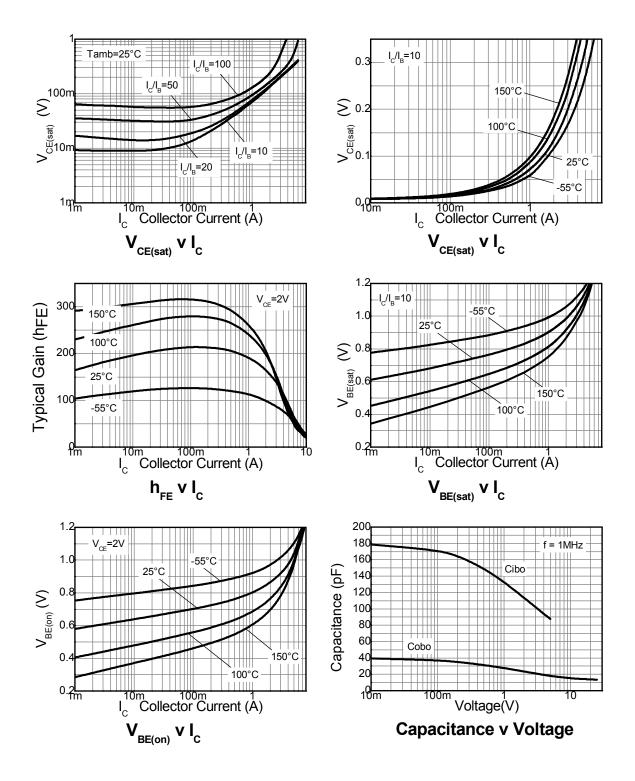
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	35	110	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	25	35	-	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	-	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	-	<1	50 0.5	nA µA	V _{CB} = 28V V _{CB} = 28V, T _A = +100°C
Emitter Cut-off Current	I _{EBO}	-	<1	50	nA	V _{EB} = 5.6V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	200 175 155 50	320 280 250 85	500 - - -	-	$\label{eq:lc} \begin{split} I_{C} &= 100 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 2 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 6 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	-	70 200	120 300	mV	$I_{C} = 1A, I_{B} = 100mA$ $I_{C} = 3A, I_{B} = 300mA$
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	-	900	1000	mV	I _C = 1A, I _B = 100mA
Base-Emitter Saturation Voltage (Note 8)	V _{BE(on)}	-	780	850	mV	$I_{C} = 1A, V_{CE} = 2V$

8. Measured under pulsed conditions. Pulse width $\leq~300\mu s.$ Duty cycle $\leq 2\%$ Notes:





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Тур

0.40

1.30

2.40

0.915

0.535

1.83

2.90

0.05

1.00

0.400

0.55

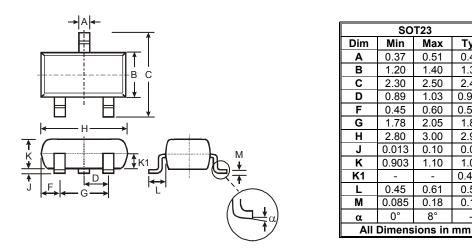
0.11

-



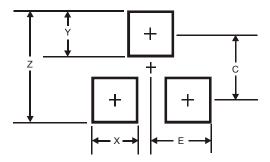
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35





ZXTN649F

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